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Kind regards,

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Very low capacitance unidirectional ESD protection diodeRev. 1 — 16 July 2012Product data set

Product data sheet

Product profile 1.

1.1 General description

Very low capacitance unidirectional ElectroStatic Discharge (ESD) protection diode designed to protect one signal line from the damage caused by ESD and other transients. The device is encapsulated in a leadless super small DSN0603-2 (SOD962) Surface-Mounted Device (SMD) package.

1.2 Features and benefits

- ESD protection of one line
- Low diode capacitance $C_d = 4 \text{ pF}$
- Super small SMD package

1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories

1.4 Quick reference data

Table 1. Quick reference data

 $T_{amb} = 25 \$ °C unless otherwise specified.

- Ultra low leakage current I_{RM} < 1 nA</p>
- ESD protection up to 12 kV
- IEC 61000-4-2; level 4 (ESD)
- Communication systems
- Portable electronics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{RWM}	reverse standoff voltage		-	-	5	V
C _d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	4	5	pF



Very low capacitance unidirectional ESD protection diode

2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	cathode	[1]	
2	anode	1 2	1 2 006aaa 152
		Transparent top view	

[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Orderin	ng information		
Type number	Package		
	Name	Description	Version
PESD5V0V1USF	DSN0603-2	leadless ultra small package; 2 terminals; body 0.6 \times 0.3 \times 0.3 mm	SOD962

4. Marking

Table 4.	Marking code	
Type num	ıber	Marking code
PESD5V0	V1USF	3

Very low capacitance unidirectional ESD protection diode

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

Table 6.ESD maximum ratings

 $T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified.

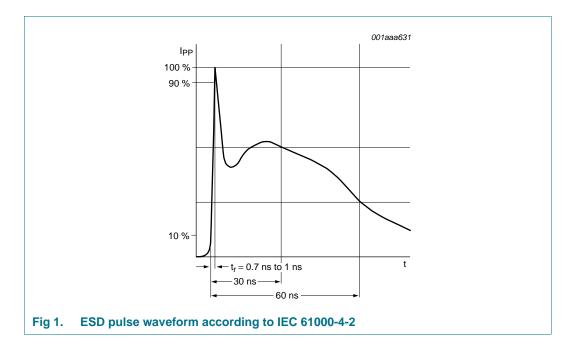
Symbol	Parameter	Conditions		Min	Max	Unit
- LOD	electrostatic	IEC 61000-4-2 (contact discharge)	[1][2]	-	12	kV
	discharge voltage	IEC 61000-4-2 (air discharge)	[1][2]	-	12	kV
		machine model	[2]	-	400	V
		MIL-STD-883 (human body model)		-	10	kV

[1] Device stressed with ten non-repetitive ESD pulses.

[2] Measured from pin 1 to pin 2.

Table 7. ESD standards compliance

Standard	Conditions
IEC 61000-4-2; level 4 (ESD)	> 8 kV (contact)
MIL-STD-883; class 3B (human body model)	> 8 kV



PESD5V0V1USF

Very low capacitance unidirectional ESD protection diode

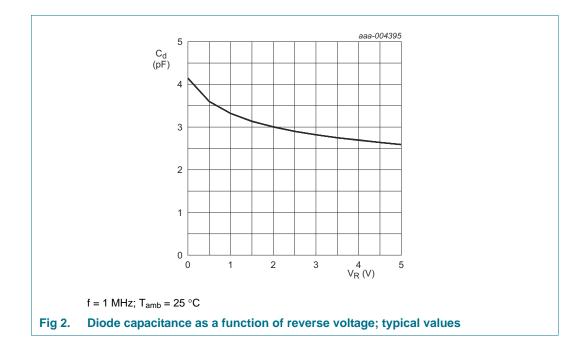
6. Characteristics

Table 8. Characteristics

 $T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified.

SymbolParameterConditionsMinTypMaxUnit V_{RWM} reverse standoff voltage5V I_{RM} reverse leakage current $V_{RWM} = 5 V$ -1100nA V_{BR} breakdown voltage $I_R = 1 \text{ mA}$ 678V C_d diode capacitance $f = 1 \text{ MHz}; V_R = 0 V$ -45pF r_{dyn} dynamic resistance $I_R = 10 \text{ A}$ [1]-2- Ω	unio	1					
voltage I_{RM} reverse leakage current $V_{RWM} = 5 V$ -1100nA V_{BR} breakdown voltage $I_R = 1 mA$ 678V C_d diode capacitancef = 1 MHz; $V_R = 0 V$ -45pF	Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{BR} breakdown voltage $I_R = 1 \text{ mA}$ 678V C_d diode capacitance $f = 1 \text{ MHz}; V_R = 0 \text{ V}$ -45pF	V_{RWM}			-	-	5	V
C_d diode capacitance $f = 1 \text{ MHz}; V_R = 0 \text{ V} - 4 5 \text{ pF}$	I _{RM}	reverse leakage current	$V_{RWM} = 5 V$	-	1	100	nA
	V_{BR}	breakdown voltage	I _R = 1 mA	6	7	8	V
r_{dyn} dynamic resistance $I_R = 10 A$ [1] - 2 - Ω	C _d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	4	5	pF
	r _{dyn}	dynamic resistance	I _R = 10 A	<u>[1]</u> _	2	-	Ω

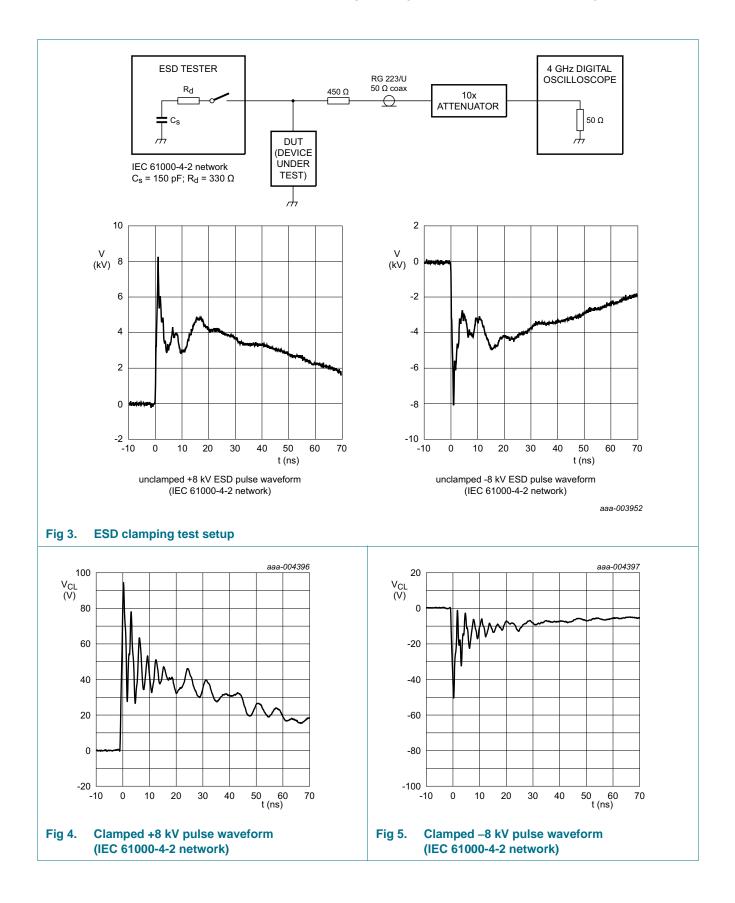
[1] Non-repetitive current pulse, Transmission Line Pulse (TLP) t_p = 100 ns; square pulse; ANS/IESD STM5-1-2008.



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PESD5V0V1USF

Very low capacitance unidirectional ESD protection diode

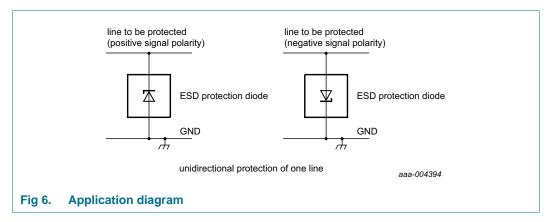


PESD5V0V1USF

Very low capacitance unidirectional ESD protection diode

7. Application information

The device is designed for the protection of one unidirectional data or signal line from surge pulses and ESD damage. The device is suitable on lines where the signal polarities are either positive or negative with respect to ground.



Circuit board layout and protection device placement

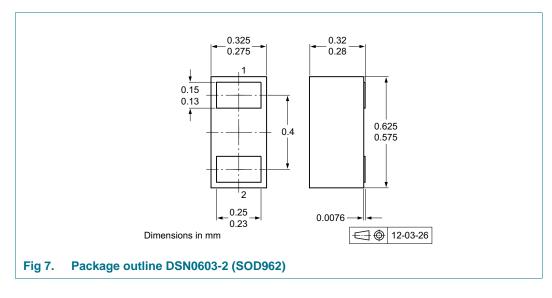
Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the device as close to the input terminal or connector as possible.
- 2. Minimize the path length between the device and the protected line.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

Product data sheet

Very low capacitance unidirectional ESD protection diode

8. Package outline



9. Packing information

Table 9. Packing methods

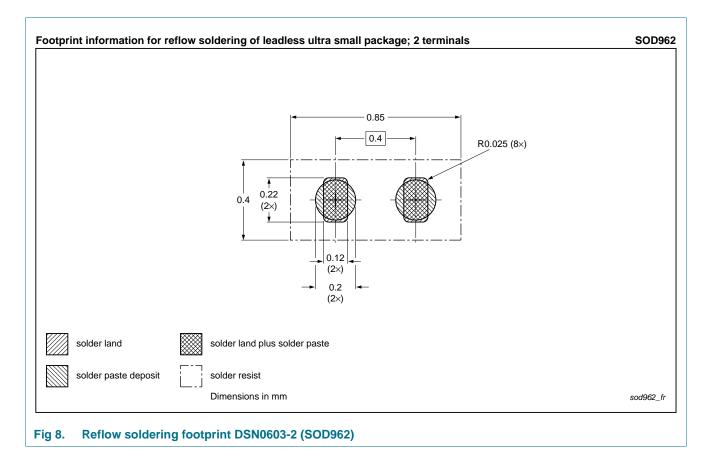
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			9000
PESD5V0V1USF	DSN0603-2 (SOD962)	2 mm pitch, 8 mm tape and reel	-315

[1] For further information and the availability of packing methods, see <u>Section 13</u>.

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10. Soldering



Very low capacitance unidirectional ESD protection diode

11. Revision history

Table 10. Revision histo	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PESD5V0V1USF v.1	20120716	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Product data sheet

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